Towards an Ultra-Low-Power Architecture Using Single-Electron Tunneling Transistors



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Executive Sumary

Motivation

- CMOS is approaching fabrication, power, and thermal limits
- Can new device technologies solve these problem?

Single electron tunneling transistor (SET)

- Unique property: lowest projected power consumption
- Challenges: fabrication for room-temperature operation, offset charge noise, etc.

Goal: investigate possible uses of SETs in low-power design

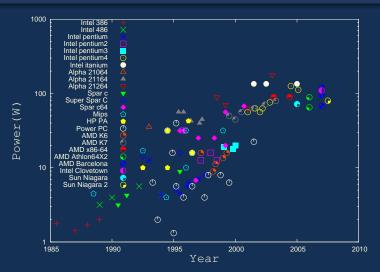
- IceFlex: fault-tolerant, SET/CMOS reconfigurable architecture
- 100× energy efficiency improvement over 22 nm CMOS
- Designed for unique challenges posed by SETs

Outline

- Introduction
 - Power, energy, and thermal challenges
- Background
 - SET properties and challenges
- Testbed design
 - IceFlex: a hybrid SET/CMOS reconfigurable architecture
- Evaluation
 - Possible uses of SETs in low-power design
- Conclusions

Power challenges

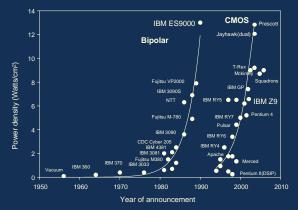
High-performance applications: energy cost, temperature, reliability Portable embedded systems: battery lifetime



What does history teach us about power consumption?

Device innovations have been the most effective method

- Vacuum tube to semiconductor device in the 1960s
- Bipolar device to CMOS transistor in the 1990s

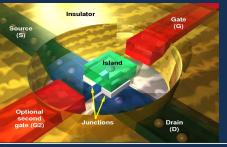


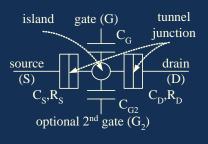
Based on diagram by C. Johnson, IBM Server and Technology Group.

Single electron tunneling transistor structure

Device structure

- Island, terminals (source, drain, gate)
- Electron tunneling through tunneling junctions





C_c:gate capacitance

C_{G2}: optional 2nd gate capacitance

:source tunnel junction capacitance

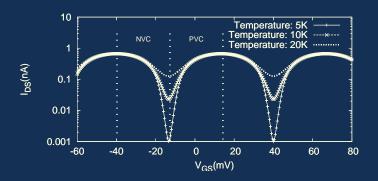
C_D: drain tunnel junction capacitance

Rs :source tunnel junction resistance R :drain tunnel junction resistance

Single electron tunneling transistor behavior

Physical principles

- Coulomb charging effect governs electron tunneling
- Coulomb blockade $V_{GS}=me/C_G$, $m=\pm 1/2,\pm 3/2,\cdots$ OFF, $m=0,\pm 1,\pm 2,\cdots$ ON



SET properties and challenges

Ultra low power

ullet Projected energy per switching event $(1 imes 10^{-18}\, ext{J})$

Room temperature and fabrication challenge

- Electrostatic charging energy must be greater than thermal energy
- $e^2/C_{\sum} > k_B T$
- ullet Requires $e^2/\mathcal{C}_{\sum} > 10 k_B T$ or even $e^2/\mathcal{C}_{\sum} > 40 k_B T$

SET properties and challenges

Performance challenge

- Electrons must be confined in the island
- $R_S, R_D > h/e^2, h/e^2 = 25.8 \, \text{k}\Omega$
- High resistance, low driving strength

Reliability concerns

- Tunneling between charge traps cause run-time errors
- Unknown before fabrication
- Device technology: Improved by silicon islands
- Reliable design: Post-fabrication adaptation
- Run-time error correction

IceFlex: low-power, fault-tolerant, hybrid SET/CMOS reconfigurable architecture

Goal

Develop a testbed to investigate possible uses of SETs in low-power embedded system design

Design metrics

Power consumption, peformance, reliability, fabrication, cooling

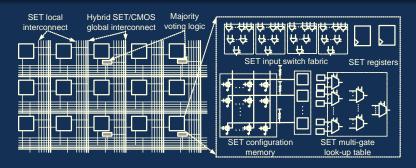
SET-specific design features

- Fabrication challenge: Regular architecture to ease fabrication
- Reliability challenge: Built-in redundancy, fault-tolerant design
- Performance challenge: Hybrid SET/CMOS design
- Unique properties: Multi-gate design for non-linearly-separable functions and voting logic

IceFlex architecture

$Fault-tolerant,\ hybrid\ SET/CMOS\ reconfigurable\ architecture$

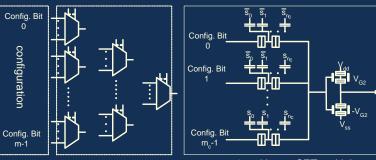
- Multi-gate SET-based reconfigurable look-up tables and switch fabric
- SET-based arithmetic unit
- SET-based reconfiguration memory
- SET threshold logic-based majority voting logic
- Hybrid SET/CMOS multi-level interconnect fabric



Multi-gate SET reconfigurable lookup table

SET multi-gate integration

- Gate charging effect: a function of $\sum C_{G_i}V_{GS_i}$
- Multiplexer design: reduce logic depth, hence circuit delay



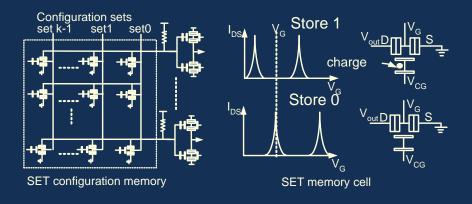
m-to-1 multi-gate multiplexer SET tree

m_c-to-1 multi-gate SET multiplexer

SET configuration memory

Multi-context on-chip storage design

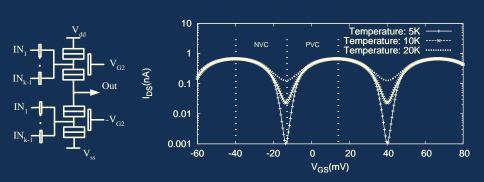
- Multi-context configuration cache
- Dual-island SET design



Efficient SET arithmetic function

SET non-unate logic

- Complicated design using threshold logic, BJT, and CMOS
- Taking advantage of the periodic nature of SET I–V characteristics



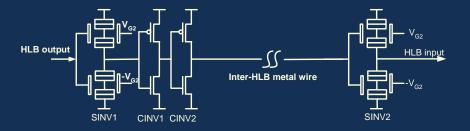
Interconnect

Local interconnect

- Requires limited driving strength
- Constant-latency, SET-based design
- Simplify physical design, i.e., routing

Global interconnect

- Requires high driving strength
- Hybrid SET/CMOS design



Potential uses of single-electron tunneling transistors

Application domains

- High-performance applications
- Battery-powered systems

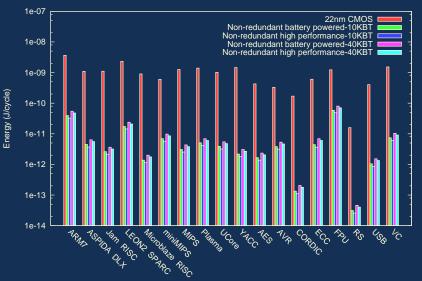
Design metrics

- Power, performance
- Fabrication, reliability

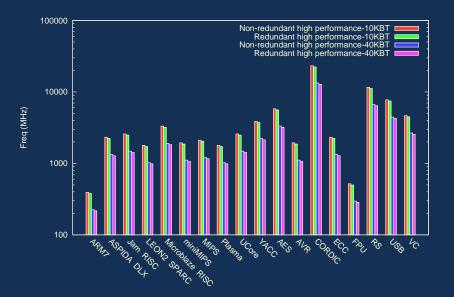
Benchmarks	Description	Benchmarks	Description
AES	AES (Rijndael) IP core	ARM7	Power-efficient RISC CPU
AVR	ATMega103 microcontroller	ASPIDA DLX	Synchronous / DLX core
CORDIC	Coordinate rotation computer	Jam RISC	Five-stage pipeline RISC CPU
ECC	ECC core	LEON2 SPARC	Entire SPARC V8 processor
FPU	32-bit IEEE 754 floating-point	Microblaze	RISC CPU
RS	Reed Solomon encoder	miniMIPS	MIPS I clone
USB	USB 2.0 function	MIPS	MIPS processor
VC	Video compression systems	Plasma	Supports most MIP I opcodes
UCore	MIPS I integer only clone	YACC	MIPS I clone

Energy efficiency

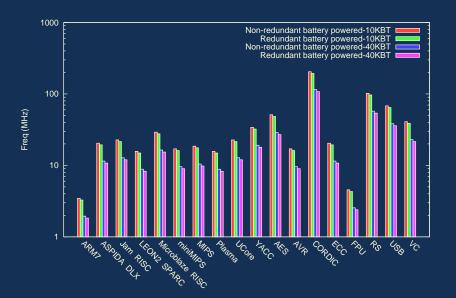
SET-based design can improve system energy efficiency by $100 \times$



IceFlex optimized for high-performance applications



IceFlex optimized for battery-powered applications



Room-temperature operation, cooling, and fabrication

		$C_{\Sigma}=e^2/(10k_BT)$		$C_{\Sigma} = e^2/(40 k_B T)$	
Temperature		Island	Island	Island	Island
(K)		capacitance	diameter	capacitance	diameter
		(aF)	(nm)	(aF)	(nm)
40	CMOS operation	4.65	52.48	1.16	13.12
77	Liquid nitrogen cooling	2.41	27.26	0.60	6.82
103	Average cloud top temp.	1.80	20.38	0.45	5.10
120	Cryogenic	1.55	17.49	0.39	4.37
200	SET device	0.93	10.50	0.23	2.62
250	Stacked Peltier heat pump	0.74	8.40	0.19	2.10
300	Room temperature	0.62	7.00	0.15	1.75

Observations

- Nanometer-scale fabrication to enable room-temperature operation
- Compact cooling design at cryogenic temperature range

Reliability

Impact of Majority Voting Logic

- MVL can significantly minimize circuit failures
- IceFlex supports Run-time failure detect and correction

SET fault probability	1/10,000			
Majority vote inputs	3	5	7	
Raw fail prob.	1/157	1/157	1/157	
SET MVL prob.	1/8,200	1/372,000	1/5,650,000	

Recent advances in device technology may greatly reduce error rate.

Estimates by Likharev in "Single-electron devices and their applications," Proc. IEEE.

Case study: High-performance parallel applications

- Assume many-core systems can be efficiently used in the future
- Given 100 W power budget
- Supports approximately 4,500 LEON2 SPARC cores at 1 GHz
- Approximately 4.8 Terra instructions per second

Case study: Battery-powered applications

Given one AA battery

IceFlex AVR can run 20 years

Given 5 cm³ scavenging volume

- Can run at max frequency from vibrations (200 µW/cm³)
- Max frequency from temperature variations (10 µW/cm³)
- 3.7 MHz from indoor solar energy (4 μW/cm³)
- 2.8 kHz from 75 dB acoustic noise $(0.003 \,\mu\text{W/cm}^3)$

Energy densities from Roundy, Wright, and Rabaey in "A Study of Low Level Vibrations as a Power Source for Wireless Sensor Nodes," Computer Communications.

Conclusions

Investigated potential of SETs in low-power system design Designed IceFlex, a low-power, fault-tolerant, hybrid SET/CMOS reconfigurable architecture

Opportunities and challenges

- Orders of magnitude power and energy efficiency improvement
- Fabrication, cooling design, and reliability challenges